## NSN 5961-00-654-3308

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View Online at https://aerobasegroup.com/nsn/5961-00-654-3308 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.359 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage and 100.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, total rms universal **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector peak **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: